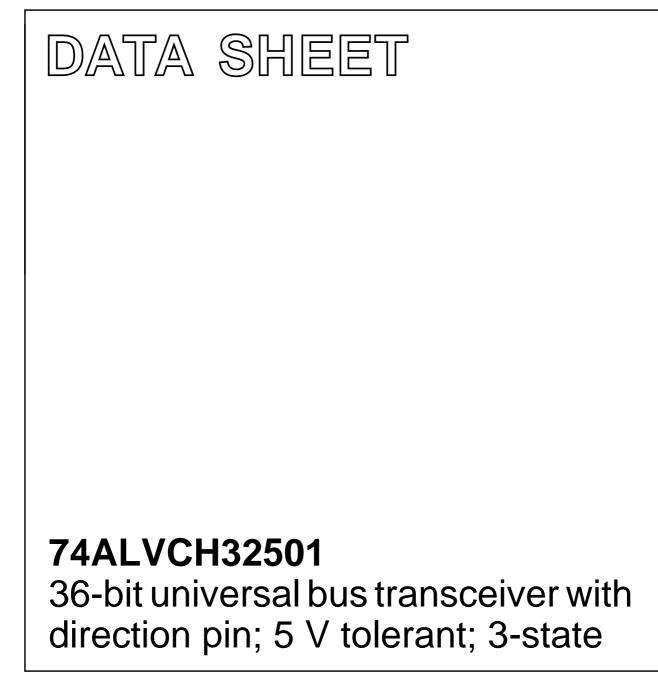
INTEGRATED CIRCUITS



Product specification File under Integrated Circuits, IC24 2000 Mar 16



#### FEATURES

- 3-state non-inverting outputs for bus oriented applications
- Wide supply voltage range of 1.2 to 3.6 V
- Complies with JEDEC standard no. 8-1A
- Current drive ±24 mA at 3.0 V
- Universal bus transceiver with D-type latches and D-type flip-flops capable of operating in transparent, latched or clocked mode
- CMOS low power consumption
- Direct interface with TTL levels
- · All inputs have bus-hold circuitry
- Output drive capability 50 Ω transmission lines at 85 °C
- Plastic fine-pitch ball grid array package.

### DESCRIPTION

The 74ALVCH32501 is a high-performance CMOS product designed for  $V_{CC}$  operation at 2.5 and 3.3 V with I/O compatibility up to 5 V.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

#### QUICK REFERENCE DATA

GND = 0 V;  $T_{amb}$  = 25 °C;  $t_r$  =  $t_f \le$  2.5 ns.

The 74ALVCH32501 can be used as two 18-bit transceivers or one 36-bit transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. Data flow in each direction is controlled by output enable ( $OE_{AB}$  and  $\overline{OE}_{BA}$ ), latch enable ( $LE_{AB}$  and  $LE_{BA}$ ), and clock inputs ( $CP_{AB}$  and  $CP_{BA}$ ). For A-to-B data flow, the device operates in the transparent mode when  $LE_{AB}$  is HIGH. When input  $LE_{AB}$  is LOW, the A data is latched if input  $CP_{AB}$  is held at a HIGH or LOW level. If input  $LE_{AB}$  is LOW, the A data is stored in the latch/flip-flop on the LOW-to-HIGH transition of  $CP_{AB}$ . When input  $OE_{AB}$  is HIGH, the outputs are active. When input  $OE_{AB}$  is LOW, the outputs are in the high-impedance state.

Data flow for B-to-A is similar to that of A-to-B, but uses inputs  $\overline{OE}_{BA}$ , LE<sub>BA</sub> and CP<sub>BA</sub>. The output enables are complimentary (OE<sub>AB</sub> is active HIGH, and  $\overline{OE}_{BA}$  is active LOW).

To ensure the high-impedance state during power-up or power-down, pin  $\overline{OE}_{BA}$  should be tied to V<sub>CC</sub> through a pull-up resistor and pin OE<sub>AB</sub> should be tied to GND through a pull-down resistor. The minimum value of the resistor is determined by the current-sinking or current-sourcing capability of the driver.

| SYMBOL                             | PARAMETER   | CONDITIONS                                      | TYP. | UNIT |
|------------------------------------|---|---|------|------|
| t <sub>PHL</sub> /t <sub>PLH</sub> | propagation delay $A_n$ to $B_n$ ; $B_n$ to $A_n$ | $C_{L} = 30 \text{ pF}; V_{CC} = 2.5 \text{ V}$ | 2.8  | ns   |
|                                    |   | $C_L = 50 \text{ pF}; V_{CC} = 3.3 \text{ V}$   | 3.0  | ns   |
| CI                                 | input capacitance                                 |   | 4.0  | pF   |
| C <sub>I/O</sub>                   | input/output capacitance                          |   | 8.0  | pF   |
| C <sub>PD</sub>                    | power dissipation capacitance per latch           | $V_I = GND$ to $V_{CC}$ ; note 1                |      |      |
|                                    |   | outputs enabled                                 | 21   | pF   |
|                                    |   | outputs disabled                                | 3    | pF   |

#### Note

1.  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$  where:

 $f_i$  = input frequency in MHz;

 $f_o = output frequency in MHz;$ 

 $C_L$  = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in Volts;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

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### FUNCTION TABLE

See notes 1 and 2.

|                   | INF               | TUT               |                 | INTERNAL  | OUTPUT          |                        |
|-------------------|-------------------|-------------------|-----------------|-----------|-----------------|------------------------|
| nOE <sub>AB</sub> | nLE <sub>AB</sub> | nCP <sub>AB</sub> | nA <sub>n</sub> | REGISTERS | nB <sub>n</sub> | OPERATING MODE         |
| L                 | Н                 | Х                 | Х               | Х         | Z               | disabled               |
| L                 | $\downarrow$      | Х                 | h               | Н         | Z               | disabled; latch data   |
| L                 | $\downarrow$      | Х                 | I               | L         | Z               |                        |
| L                 | L                 | H or L            | Х               | NC        | Z               | disabled; hold data    |
| L                 | L                 | $\uparrow$        | h               | Н         | Z               | disabled; clock data   |
| L                 | L                 | $\uparrow$        | I               | L         | Z               |                        |
| Н                 | Н                 | Х                 | Н               | Н         | Н               | transparent            |
| н                 | Н                 | Х                 | L               | L         | L               |                        |
| Н                 | $\downarrow$      | Х                 | h               | Н         | Н               | latch data and display |
| н                 | $\downarrow$      | Х                 | I               | L         | L               |                        |
| Н                 | L                 | $\uparrow$        | h               | Н         | Н               | clock data and display |
| н                 | L                 | $\uparrow$        | I               | L         | L               |                        |
| Н                 | L                 | H or L            | Х               | Н         | Н               | hold data and display  |
| Н                 | L                 | H or L            | Х               | L         | L               |                        |

#### Notes

1. A-to-B data flow is shown; B-to-A flow is similar but uses  $n\overline{OE}_{BA}$ ,  $nLE_{BA}$  and  $nCP_{BA}$ .

2. H = HIGH voltage level;

h = HIGH voltage level on set-up time prior to the enable or clock transition;

L = LOW voltage level;

I = LOW voltage level on set-up time prior to the enable or clock transition;

NC = no change;

X = don't care;

- $\uparrow$  = LOW-to-HIGH enable or clock transition;
- $\downarrow$  = HIGH-to-LOW enable or clock transition;
- Z = high impedance OFF-state.

## 74ALVCH32501

### **ORDERING INFORMATION**

|                |                      |      | PACKAGE  |          |          |
|----------------|----------------------|------|----------|----------|----------|
| TYPE NUMBER    | TEMPERATURE<br>RANGE | PINS | PACKAGE  | MATERIAL | CODE     |
| 74ALVCH32501EC | –40 to +85 °C        | 114  | LFBGA114 | plastic  | SOT537-1 |

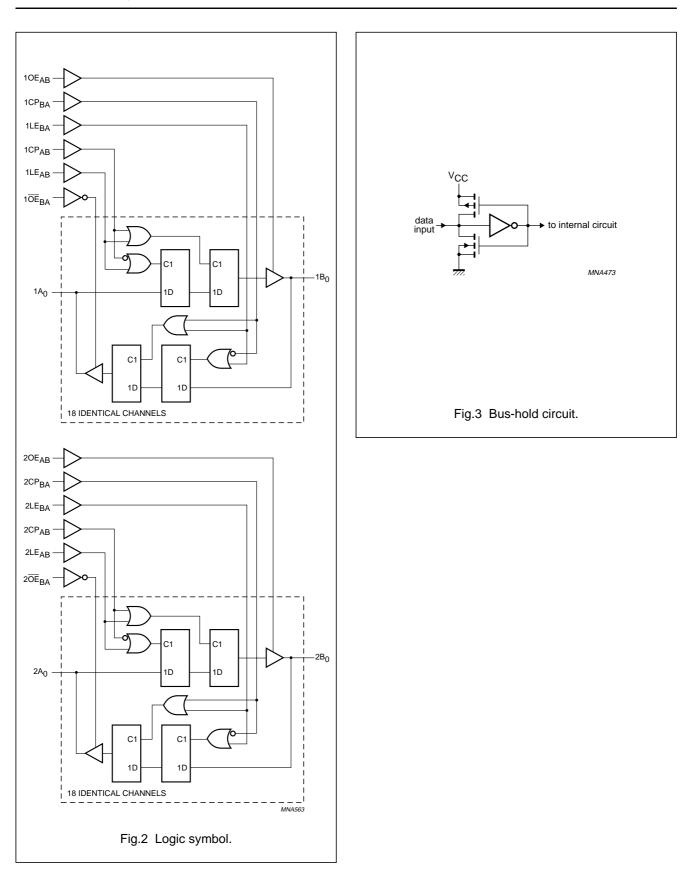
### PINNING

| SYMBOL            | DESCRIPTION                               |
|-------------------|---|
| nA <sub>n</sub>   | data inputs                               |
| nB <sub>n</sub>   | data outputs                              |
| GND               | ground (0 V)                              |
| V <sub>CC</sub>   | DC supply voltage                         |
| nOE <sub>AB</sub> | output enable inputs A to B (active HIGH) |
| nOE <sub>BA</sub> | output enable inputs B to A (active LOW)  |
| nLE <sub>AB</sub> | latch enable inputs A to B                |
| nLE <sub>BA</sub> | latch enable inputs B to A                |
| nCP <sub>AB</sub> | clock input A to B                        |
| nCP <sub>BA</sub> | clock input B to A                        |

| 6 | 1B <sub>1</sub>   | 1B3               | 1B <sub>5</sub> | 1B <sub>7</sub> | 1B <sub>9</sub> | 1B <sub>11</sub> | 1B <sub>13</sub> | 1B <sub>14</sub> | 1B <sub>16</sub>  | n.c.              | 2B <sub>1</sub>   | 2B3             | 2B5             | 2B7             | 2B9             | 2B <sub>11</sub> | 2B <sub>13</sub> | 2B14             | 2B <sub>16</sub>  |
|---|-------------------|-------------------|-----------------|-----------------|-----------------|------------------|------------------|------------------|-------------------|-------------------|-------------------|-----------------|-----------------|-----------------|-----------------|------------------|------------------|------------------|-------------------|
| 5 | 1B <sub>0</sub>   | 1B <sub>2</sub>   | 1B <sub>4</sub> | 1B <sub>6</sub> | 1B <sub>8</sub> | 1B <sub>10</sub> | 1B <sub>12</sub> | 1B <sub>15</sub> | 1B <sub>17</sub>  | 2CP <sub>AB</sub> | 2B <sub>0</sub>   | 28 <sub>2</sub> | 2B <sub>4</sub> | 2B <sub>6</sub> | 28 <sub>8</sub> | 2B <sub>10</sub> | 2B <sub>12</sub> | 2B <sub>15</sub> | 2B <sub>17</sub>  |
| 4 | 1CP <sub>AB</sub> | GND               | GND             | VCC             | GND             | GND              | Vcc              | GND              | 1CP <sub>BA</sub> | GND               | GND               | GND             | v <sub>cc</sub> | GND             | GND             | Vcc              | GND              | 2CPBA            | GND               |
| 3 | 1LE <sub>AB</sub> | 10E <sub>AB</sub> | GND             | VCC             | GND             | GND              | Vcc              | GND              |                   | 1LE <sub>BA</sub> | 20E <sub>AB</sub> | GND             | v <sub>cc</sub> | GND             | GND             | v <sub>cc</sub>  | GND              |                  | 2LE <sub>BA</sub> |
| 2 | 1A <sub>0</sub>   | 1A <sub>2</sub>   | 1A <sub>4</sub> | 1A <sub>6</sub> | 1A <sub>8</sub> | 1A <sub>10</sub> | 1A <sub>12</sub> | 1A <sub>15</sub> | 1A <sub>17</sub>  | 2LE <sub>AB</sub> | 2A <sub>0</sub>   | 2A <sub>2</sub> | 2A4             | 2A <sub>6</sub> | 2A8             | 2A <sub>10</sub> | 2A <sub>12</sub> | 2A <sub>15</sub> | 2A <sub>17</sub>  |
| 1 | 1A <sub>1</sub>   | 1A <sub>3</sub>   | 1A <sub>5</sub> | 1A <sub>7</sub> | 1Ag             | 1A <sub>11</sub> | 1A <sub>13</sub> | 1A <sub>14</sub> | 1A <sub>16</sub>  | n.c.              | 2A <sub>1</sub>   | 2A3             | 2A5             | 2A7             | 2A9             | 2A <sub>11</sub> | 2A <sub>13</sub> | 2A <sub>14</sub> | 2A <sub>16</sub>  |
|   | A                 | В                 | С               | D               | E               | F                | G                | н                | J                 | к                 | L                 | М               | N               | Р               | R               | т                | U                | V                | w                 |

Fig.1 Pin configuration.

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### 74ALVCH32501

### **RECOMMENDED OPERATING CONDITIONS**

| SYMBOL                          | PARAMETER                       | CONDITIONS   | MIN. | MAX.            | UNIT |
|---------------------------------|---------------------------------|--|------|-----------------|------|
| V <sub>CC</sub>                 | DC supply voltage               | 2.5 V range (for maximum speed performance at 30 pF output load) | 2.3  | 2.7             | V    |
|                                 |                                 | 3.3 V range (for maximum speed performance at 50 pF output load) | 3.0  | 3.6             | V    |
| VI                              | DC input voltage                |  | 0    | V <sub>CC</sub> | V    |
| Vo                              | DC output voltage               | output HIGH or LOW state   | 0    | V <sub>CC</sub> | V    |
| T <sub>amb</sub>                | ambient temperature             |  | -40  | +85             | °C   |
| t <sub>r</sub> , t <sub>f</sub> | input rise and fall time ratios | V <sub>CC</sub> = 1.2 to 2.7 V                                   | 0    | 20              | ns/V |
|                                 | $(\Delta t/\Delta V)$           | V <sub>CC</sub> = 2.7 to 3.6 V                                   | 0    | 10              | ns/V |

### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

| SYMBOL                             | PARAMETER                        | CONDITIONS                                      | MIN. | MAX.                  | UNIT |
|------------------------------------|----------------------------------|---|------|-----------------------|------|
| V <sub>CC</sub>                    | DC supply voltage                |   | -0.5 | +4.6                  | V    |
| VI                                 | DC input voltage                 | for control pins; note 1                        | -0.5 | +4.6                  | V    |
|                                    |                                  | for data input pins; note 1                     | -0.5 | V <sub>CC</sub> + 0.5 | V    |
| I <sub>IK</sub>                    | DC input diode current           | V <sub>1</sub> < 0                              | -    | -50                   | mA   |
| I <sub>OK</sub>                    | DC output clamping diode current | V <sub>O</sub> < 0; note 1                      | -    | 50                    | mA   |
| Vo                                 | DC output voltage                | see note 1                                      | -0.5 | V <sub>CC</sub> + 0.5 | V    |
| lo                                 | DC output sink current           | $V_{O} = 0$ to $V_{CC}$                         | -    | -50                   | mA   |
| I <sub>CC</sub> , I <sub>GND</sub> | DC $V_{CC}$ or GND current       |   | _    | ±100                  | mA   |
| T <sub>stg</sub>                   | storage temperature              |   | -65  | +150                  | °C   |
| P <sub>D</sub>                     | power dissipation per packages   | for temperature range:<br>-40 to +85 °C; note 2 | _    | 1000                  | mW   |

### Notes

- 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.
- 2. Above 55 °C the value of  $\mathsf{P}_\mathsf{D}$  derates linearly with 1.8 mW/K.

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### **DC CHARACTERISTICS**

Over recommended operating conditions; voltages are referenced to GND (ground = 0 V).

|                   |   | TEST CONDITIO   | NS                  |                       | T <sub>amb</sub> (°C)      |      |    |  |
|-------------------|---|---|---------------------|-----------------------|----------------------------|------|----|--|
| SYMBOL            | PARAMETER   |   |                     |                       | –40 to +85                 |      |    |  |
|                   |   | OTHER   | V <sub>CC</sub> (V) | MIN.                  | <b>TYP.</b> <sup>(1)</sup> | MAX. | 1  |  |
| VIH               | HIGH-level input  |   | 2.3 to 2.7          | 1.7                   | 1.2                        | _    | V  |  |
|                   | voltage   |   | 2.7 to 3.6          | 2.0                   | 1.5                        | -    | V  |  |
| V <sub>IL</sub>   | LOW-level input   |   | 2.3 to 2.7          | -                     | 1.2                        | 0.7  | V  |  |
|                   | voltage   |   | 2.7 to 3.6          | -                     | 1.5                        | 0.8  | V  |  |
| V <sub>OH</sub>   | HIGH-level output   | $V_{I} = V_{IH} \text{ or } V_{IL}$   |                     |                       |                            |      |    |  |
|                   | voltage   | I <sub>O</sub> = -100 μA  | 2.3 to 3.6          | V <sub>CC</sub> - 0.2 | V <sub>CC</sub>            | _    | V  |  |
|                   |   | $I_0 = -6 \text{ mA}$   | 2.3                 | $V_{CC} - 0.3$        | V <sub>CC</sub> - 0.08     | _    | V  |  |
|                   |   | I <sub>O</sub> = -12 mA   | 2.3                 | V <sub>CC</sub> - 0.6 | V <sub>CC</sub> - 0.26     | _    | V  |  |
|                   |   | I <sub>O</sub> = -12 mA   | 2.7                 | $V_{CC} - 0.5$        | V <sub>CC</sub> - 0.14     | -    | V  |  |
|                   |   | $I_0 = -12 \text{ mA}$  | 3.0                 | $V_{CC} - 0.6$        | V <sub>CC</sub> - 0.09     | _    | V  |  |
|                   |   | I <sub>O</sub> = -24 mA   | 3.0                 | V <sub>CC</sub> – 1.0 | V <sub>CC</sub> - 0.28     | -    | V  |  |
| V <sub>OL</sub>   | LOW-level output  | $V_{I} = V_{IH} \text{ or } V_{IL}$   |                     |                       |                            |      |    |  |
|                   | voltage   | I <sub>O</sub> = 100 μA   | 2.3 to 3.6          | _                     | GND                        | 0.20 | V  |  |
|                   |   | I <sub>O</sub> = 6 mA   | 2.3                 | -                     | 0.07                       | 0.40 | V  |  |
|                   |   | I <sub>O</sub> = 12 mA  | 2.3                 | _                     | 0.15                       | 0.70 | V  |  |
|                   |   | I <sub>O</sub> = 12 mA  | 2.7                 | _                     | 0.14                       | 0.40 | V  |  |
|                   |   | I <sub>O</sub> = 24 mA  | 3.0                 | -                     | 0.27                       | 0.55 | V  |  |
| l                 | input leakage current   | $V_{I} = V_{CC}$ or GND   | 2.3 to 3.6          | -                     | ±0.1                       | ±5   | μA |  |
| I <sub>OZ</sub>   | 3-state output<br>OFF-state current   | $V_{I} = V_{IH} \text{ or } V_{IL};$<br>$V_{O} = V_{CC} \text{ or GND; note 2}$ | 2.3 to 3.6          | -                     | 0.1                        | ±10  | μA |  |
| I <sub>CC</sub>   | quiescent supply<br>current   | $V_{I} = V_{CC}$ or GND; $I_{O} = 0$  | 2.3 to 3.6          | -                     | 0.4                        | 80   | μA |  |
| ΔI <sub>CC</sub>  | additional quiescent<br>supply current given<br>per data I/O pin with<br>bus-hold | $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0$                                     | 2.7 to 3.6          | _                     | 150                        | 750  | μA |  |
| I <sub>BHL</sub>  | bus-hold LOW  | V <sub>I</sub> = 0.7 V; note 3  | 2.3                 | 45                    | _                          | -    | μA |  |
|                   | sustaining current  | V <sub>I</sub> = 0.8 V; note 3  | 3.0                 | 75                    | 150                        | _    | μA |  |
| I <sub>BHH</sub>  | bus-hold HIGH   | V <sub>I</sub> = 1.7 V; note 3  | 2.3                 | -45                   | _                          | -    | μA |  |
|                   | sustaining current  | V <sub>I</sub> = 2.0 V; note 3  | 3.0                 | -75                   | -175                       | _    | μA |  |
| I <sub>BHLO</sub> | bus-hold LOW<br>overdrive current   | note 3  | 3.6                 | 500                   | -                          | -    | μA |  |
| I <sub>BHHO</sub> | bus-hold HIGH<br>overdrive current  | note 3  | 3.6                 | -500                  | -                          | -    | μA |  |

### Notes

1. All typical values are at V\_{CC} = 3.3 V and T\_{amb} = 25 °C.

2. For I/O ports, the parameter  $I_{\text{OZ}}$  includes the input leakage current.

3. Valid for data inputs of bus-hold parts.

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### AC CHARACTERISTICS

#### GND = 0 V

| SAMBO                              | DADAMETED   | TEST CONDIT      | T <sub>amb</sub> : |      |      |      |     |
|------------------------------------|---|------------------|--------------------|------|------|------|-----|
| SYMBOL                             | PARAMETER   | WAVEFORMS        | CL                 | MIN. | TYP. | MAX. |     |
| $V_{\rm CC} = 2.3 \ {\rm tc}$      | <b>o 2.7 V; t<sub>r</sub> = t<sub>f</sub> ≤ 2.0 ns;</b> note 1                                      | ·                |                    |      |      |      |     |
| t <sub>PHL</sub> /t <sub>PLH</sub> | propagation delay   |                  |                    |      |      |      |     |
|                                    | nA <sub>n</sub> to nB <sub>n</sub> ; nB <sub>n</sub> to nA <sub>n</sub>                             | see Figs 4 and 8 | 30 pF              | 1.0  | 2.8  | 5.1  | ns  |
|                                    | nLE <sub>BA</sub> to nA <sub>n</sub> ; nLE <sub>AB</sub> to nB <sub>n</sub>                         | see Figs 5 and 8 |                    | 1.1  | 3.5  | 6.1  | ns  |
|                                    | nCP <sub>BA</sub> to nA <sub>n</sub> ; nCP <sub>AB</sub> to nB <sub>n</sub>                         | see Figs 5 and 8 |                    | 1.0  | 3.3  | 6.1  | ns  |
| t <sub>PZH</sub> /t <sub>PZL</sub> | 3-state output enable time nOE <sub>AB</sub> to nB <sub>n</sub>                                     | see Figs 6 and 8 |                    | 1.0  | 2.5  | 5.8  | ns  |
|                                    | 3-state output enable time $n\overline{OE}_{BA}$ to $nA_n$  | see Figs 6 and 8 |                    | 1.3  | 2.8  | 6.3  | ns  |
| t <sub>PHZ</sub> /t <sub>PLZ</sub> | 3-state output disable time nOE <sub>AB</sub> to nB <sub>n</sub>                                    | see Figs 6 and 8 |                    | 1.5  | 2.5  | 6.2  | ns  |
|                                    | 3-state output disable time $n\overline{OE}_{BA}$ to $nA_n$   | see Figs 6 and 8 |                    | 1.3  | 2.5  | 5.3  | ns  |
| t <sub>W</sub>                     | nLE <sub>AB</sub> or nLE <sub>BA</sub> pulse width HIGH   | see Figs 5 and 8 |                    | 3.3  | 0.8  | _    | ns  |
|                                    | nCP <sub>AB</sub> or nCP <sub>BA</sub> pulse width<br>HIGH or LOW                                   | see Figs 5 and 8 |                    | 3.3  | 2.0  | -    | ns  |
| t <sub>su</sub>                    | set-up time $nA_n$ before $nCP_{AB}^{\uparrow}$ or $nB_n$ before $nCP_{BA}^{\uparrow}$              | see Figs 7 and 8 |                    | 1.7  | 0.1  | -    | ns  |
|                                    | set-up time CP HIGH or LOW $nA_n$ before $nLE_{AB}\downarrow$ or $nB_n$ before $nLE_{BA}\downarrow$ | see Figs 7 and 8 |                    | 1.1  | 0.1  | -    | ns  |
| t <sub>h</sub>                     | hold time $nA_n$ after $nCP_{AB}^{\uparrow}$ or $nB_n$ after $nCP_{BA}^{\uparrow}$                  | see Figs 7 and 8 |                    | 1.7  | 0.3  | -    | ns  |
|                                    | hold time CP HIGH or LOW $nA_n$ after $nLE_{AB}\downarrow$ or $nB_n$ after $nLE_{BA}\downarrow$     | see Figs 7 and 8 |                    | 1.6  | 0.3  | -    | ns  |
| f <sub>max</sub>                   | maximum clock frequency   | see Figs 5 and 8 |                    | 150  | 330  | _    | MHz |
| $V_{CC} = 2.7 V$                   | ; <b>t</b> <sub>r</sub> = <b>t</b> <sub>f</sub> ≤ <b>2.5 ns</b> ; note 2                            | ·                |                    |      |      |      |     |
| t <sub>PHL</sub> /t <sub>PLH</sub> | propagation delay   |                  |                    |      |      |      |     |
|                                    | nA <sub>n</sub> to nB <sub>n</sub> ; nB <sub>n</sub> to nA <sub>n</sub>                             | see Figs 4 and 8 | 50 pF              | _    | 3.0  | 4.6  | ns  |
|                                    | $nLE_{BA}$ to $nA_n$ ; $nLE_{AB}$ to $nB_n$   | see Figs 5 and 8 |                    | _    | 3.6  | 5.3  | ns  |
|                                    | $nCP_{BA}$ to $nA_n$ ; $nCP_{AB}$ to $nB_n$   | see Figs 5 and 8 |                    | _    | 3.4  | 5.6  | ns  |
| t <sub>PZH</sub> /t <sub>PZL</sub> | 3-state output enable time nOE <sub>AB</sub> to nB <sub>n</sub>                                     | see Figs 6 and 8 | 1                  | _    | 2.7  | 5.3  | ns  |
|                                    | 3-state output enable time $n\overline{OE}_{BA}$ to $nA_n$  | see Figs 6 and 8 | 1                  | _    | 3.3  | 6.0  | ns  |
| t <sub>PHZ</sub> /t <sub>PLZ</sub> | 3-state output disable time nOE <sub>AB</sub> to nB <sub>n</sub>                                    | see Figs 6 and 8 | 1                  | _    | 3.6  | 5.7  | ns  |
|                                    | 3-state output disable time $n\overline{OE}_{BA}$ to $nA_n$   | see Figs 6 and 8 | 1                  | _    | 3.3  | 4.6  | ns  |
| t <sub>W</sub>                     | pulse width nLE <sub>AB</sub> or nLE <sub>BA</sub> HIGH   | see Figs 5 and 8 | 1                  | 3.3  | 0.7  | -    | ns  |
|                                    | pulse width nCP <sub>AB</sub> or nCP <sub>BA</sub><br>HIGH or LOW                                   | see Figs 5 and 8 |                    | 3.3  | 1.4  | -    | ns  |

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| CVMDO!                             |   | TEST CONDIT      | T <sub>amb</sub> : | = –40 to | +85 °C |      |     |
|------------------------------------|---|------------------|--------------------|----------|--------|------|-----|
| SYMBOL                             | PARAMETER   | WAVEFORMS        | CL                 | MIN.     | TYP.   | MAX. |     |
| t <sub>su</sub>                    | set-up time $nA_n$ before $nCP_{AB}^{\uparrow}$ or $nB_n$ before $nCP_{BA}^{\uparrow}$              | see Figs 7 and 8 | 50 pF              | +1.4     | -0.1   | -    | ns  |
|                                    | set-up time CP HIGH or LOW $nA_n$ before $nLE_{AB}\downarrow$ or $nB_n$ before $nLE_{BA}\downarrow$ | see Figs 7 and 8 |                    | +1.0     | -0.2   | -    | ns  |
| t <sub>h</sub>                     | hold time $nA_n$ after $nCP_{AB}^{\uparrow}$ or $nB_n$ after $nCP_{BA}^{\uparrow}$                  | see Figs 7 and 8 |                    | 1.6      | 0.3    | -    | ns  |
|                                    | hold time CP HIGH or LOW $nA_n$ after $nLE_{AB}\downarrow$ or $nB_n$ after $nLE_{BA}\downarrow$     | see Figs 7 and 8 |                    | 1.5      | 0.1    | -    | ns  |
| f <sub>max</sub>                   | maximum clock frequency   | see Figs 5 and 8 |                    | 150      | 333    | -    | MHz |
| $V_{CC} = 3.0$ to                  | <b>9 3.6 V;</b> $\mathbf{t}_r = \mathbf{t}_f \le$ <b>2.5 ns;</b> note 3                             |                  |                    |          |        |      |     |
| t <sub>PHL</sub> /t <sub>PLH</sub> | propagation delay   |                  |                    |          |        |      |     |
|                                    | nA <sub>n</sub> to nB <sub>n</sub> ; nB <sub>n</sub> to nA <sub>n</sub>                             | see Figs 4 and 8 | 50 pF              | 1.0      | 3.0    | 4.2  | ns  |
|                                    | $nLE_{BA}$ to $nA_n$ ; $nLE_{AB}$ to $nB_n$   | see Figs 5 and 8 |                    | 1.3      | 3.4    | 4.8  | ns  |
|                                    | nCP <sub>BA</sub> to nA <sub>n</sub> ; nCP <sub>AB</sub> to nB <sub>n</sub>                         | see Figs 5 and 8 |                    | 1.4      | 3.3    | 4.9  | ns  |
| t <sub>PZH</sub> /t <sub>PZL</sub> | 3-state output enable time nOE <sub>AB</sub> to nB <sub>n</sub>                                     | see Figs 6 and 8 |                    | 1.0      | 2.4    | 4.6  | ns  |
|                                    | 3-state output enable time $n\overline{OE}_{BA}$ to $nA_n$  | see Figs 6 and 8 | 1                  | 1.1      | 2.5    | 5.0  | ns  |
| t <sub>PHZ</sub> /t <sub>PLZ</sub> | 3-state output disable time nOE <sub>AB</sub> to nB <sub>n</sub>                                    | see Figs 6 and 8 |                    | 1.4      | 2.9    | 5.0  | ns  |
|                                    | 3-state output disable time $n\overline{OE}_{BA}$ to $nA_n$   | see Figs 6 and 8 |                    | 1.3      | 3.1    | 4.2  | ns  |
| t <sub>W</sub>                     | pulse width nLE <sub>AB</sub> or nLE <sub>BA</sub> HIGH   | see Figs 5 and 8 |                    | 3.3      | 0.9    | _    | ns  |
|                                    | pulse width nCP <sub>AB</sub> or nCP <sub>BA</sub><br>HIGH or LOW                                   | see Figs 5 and 8 |                    | 3.3      | 1.1    | -    | ns  |
| t <sub>su</sub>                    | set-up time $nA_n$ before $nCP_{AB}^{\uparrow}$ or $nB_n$ before $nCP_{BA}^{\uparrow}$              | see Figs 7 and 8 |                    | +1.3     | -0.3   | -    | ns  |
|                                    | set-up time CP HIGH or LOW $nA_n$ before $nLE_{AB}\downarrow$ or $nB_n$ before $nLE_{BA}\downarrow$ | see Figs 7 and 8 |                    | 1.0      | 0.3    | -    | ns  |
| t <sub>h</sub>                     | hold time $nA_n$ after $nCP_{AB}^{\uparrow}$ or $nB_n$ after $nCP_{BA}^{\uparrow}$                  | see Figs 7 and 8 |                    | +1.3     | -0.4   | _    | ns  |
|                                    | hold time CP HIGH or LOW $nA_n$ after $nLE_{AB}\downarrow$ or $nB_n$ after $nLE_{BA}\downarrow$     | see Figs 7 and 8 |                    | 1.2      | 0.1    | -    | ns  |
| f <sub>max</sub>                   | maximum clock frequency   | see Figs 5 and 8 |                    | 150      | 340    | _    | MHz |

### Notes

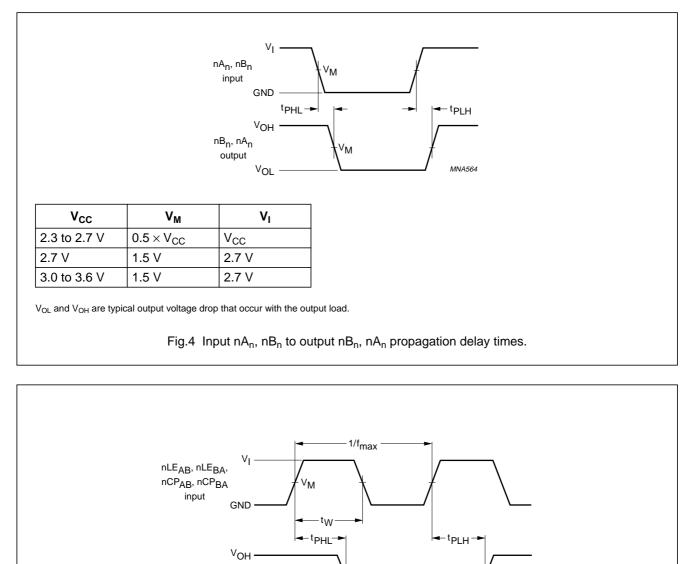
1. All typical values are measured at V\_{CC} = 2.5 V and T\_{amb} = 25 °C.

2. All typical values are measured at  $T_{amb}$  = 25  $^{\circ}C.$ 

3. All typical values are measured at V\_{CC} = 3.3 V and T\_{amb} = 25 °C.

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### AC WAVEFORMS



| V <sub>cc</sub> | V <sub>M</sub>      | VI              |
|-----------------|---------------------|-----------------|
| 2.3 to 2.7 V    | $0.5 \times V_{CC}$ | V <sub>CC</sub> |
| 2.7 V           | 1.5 V               | 2.7 V           |
| 3.0 to 3.6 V    | 1.5 V               | 2.7 V           |

nA<sub>n</sub>, nB<sub>n</sub>

output

 $V_{OL}$ 

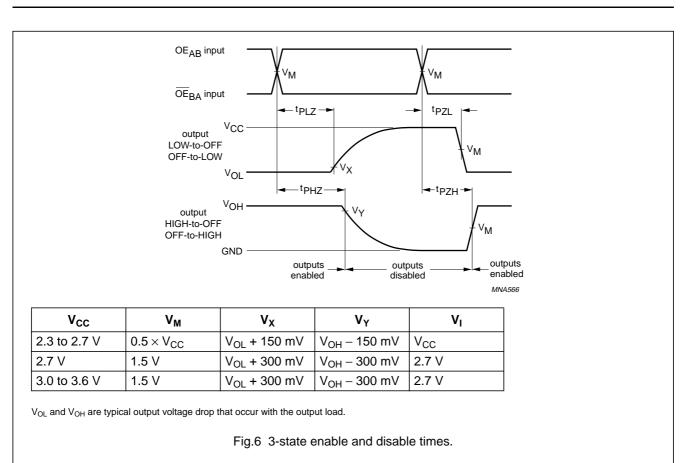
 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage drop that occur with the output load.

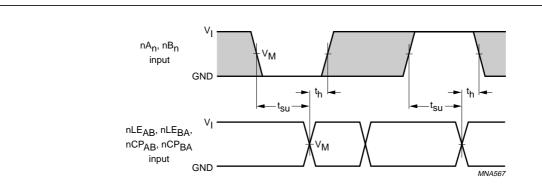
Fig.5 Latch enable input (nLE<sub>AB</sub>, nLE<sub>BA</sub>) and clock input (nCP<sub>AB</sub>, nCP<sub>BA</sub>) to output propagation delays and their pulse width.

Vм

MNA565

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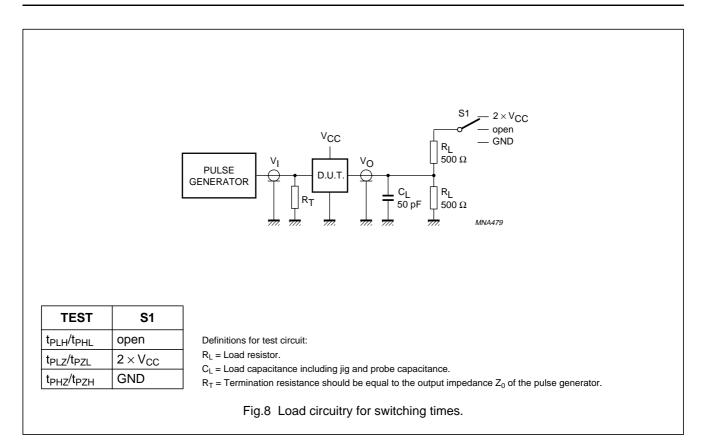
The shaded areas indicate when the input is permitted to change for predictable output performance.

| V <sub>CC</sub> | V <sub>M</sub>      | VI              |
|-----------------|---------------------|-----------------|
| 2.3 to 2.7 V    | $0.5 \times V_{CC}$ | V <sub>CC</sub> |
| 2.7 V           | 1.5 V               | 2.7 V           |
| 3.0 to 3.6 V    | 1.5 V               | 2.7 V           |

 $V_{\text{OL}}$  and  $V_{\text{OH}}$  are typical output voltage drop that occur with the output load.

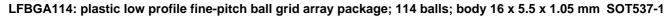
Fig.7 Data set-up and hold times for the  $nA_n$  and  $nB_n$  inputs to the  $nLE_{AB}$ ,  $nLE_{BA}$ ,  $nCP_{AB}$  and  $nCP_{BA}$  inputs.

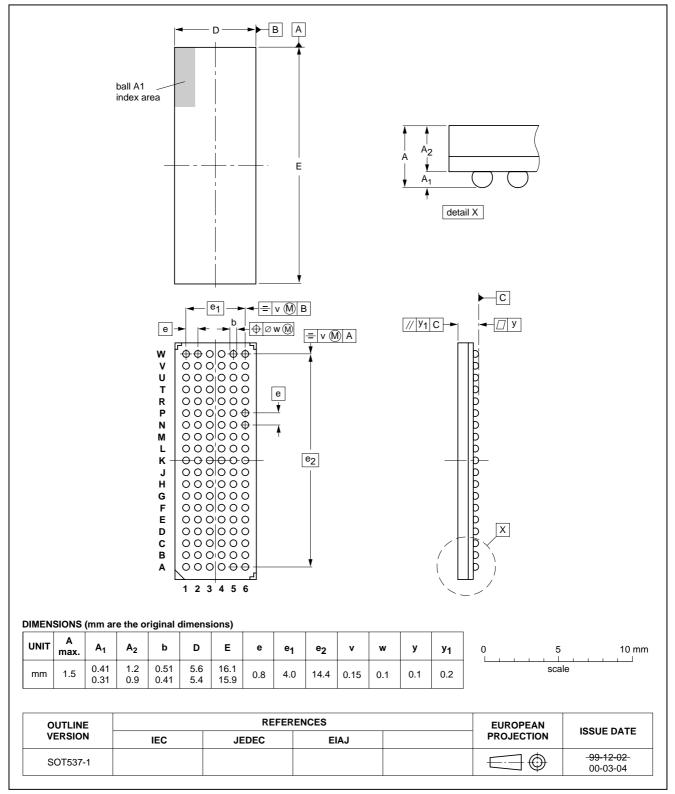
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### PACKAGE OUTLINE





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### SOLDERING

#### Introduction to soldering surface mount packages

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"Data Handbook IC26; Integrated Circuit Packages"* (document order number 9398 652 90011).

There is no soldering method that is ideal for all surface mount IC packages. Wave soldering is not always suitable for surface mount ICs, or for printed-circuit boards with high population densities. In these situations reflow soldering is often used.

#### **Reflow soldering**

Reflow soldering requires solder paste (a suspension of fine solder particles, flux and binding agent) to be applied to the printed-circuit board by screen printing, stencilling or pressure-syringe dispensing before package placement.

Several methods exist for reflowing; for example, infrared/convection heating in a conveyor type oven. Throughput times (preheating, soldering and cooling) vary between 100 and 200 seconds depending on heating method.

Typical reflow peak temperatures range from 215 to 250 °C. The top-surface temperature of the packages should preferable be kept below 230 °C.

### Wave soldering

Conventional single wave soldering is not recommended for surface mount devices (SMDs) or printed-circuit boards with a high component density, as solder bridging and non-wetting can present major problems.

To overcome these problems the double-wave soldering method was specifically developed.

If wave soldering is used the following conditions must be observed for optimal results:

- Use a double-wave soldering method comprising a turbulent wave with high upward pressure followed by a smooth laminar wave.
- For packages with leads on two sides and a pitch (e):
  - larger than or equal to 1.27 mm, the footprint longitudinal axis is preferred to be parallel to the transport direction of the printed-circuit board;
  - smaller than 1.27 mm, the footprint longitudinal axis must be parallel to the transport direction of the printed-circuit board.

The footprint must incorporate solder thieves at the downstream end.

• For packages with leads on four sides, the footprint must be placed at a 45° angle to the transport direction of the printed-circuit board. The footprint must incorporate solder thieves downstream and at the side corners.

During placement and before soldering, the package must be fixed with a droplet of adhesive. The adhesive can be applied by screen printing, pin transfer or syringe dispensing. The package can be soldered after the adhesive is cured.

Typical dwell time is 4 seconds at 250 °C. A mildly-activated flux will eliminate the need for removal of corrosive residues in most applications.

#### Manual soldering

Fix the component by first soldering two diagonally-opposite end leads. Use a low voltage (24 V or less) soldering iron applied to the flat part of the lead. Contact time must be limited to 10 seconds at up to  $300 \,^{\circ}$ C.

When using a dedicated tool, all other leads can be soldered in one operation within 2 to 5 seconds between 270 and 320  $^\circ\text{C}.$ 

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### Suitability of surface mount IC packages for wave and reflow soldering methods

| PACKAGE                                      | SOLDERING METHOD                  |                       |
|--|-----------------------------------|-----------------------|
|  | WAVE                              | REFLOW <sup>(1)</sup> |
| BGA, LFBGA, SQFP, TFBGA                      | not suitable                      | suitable              |
| HBCC, HLQFP, HSQFP, HSOP, HTQFP, HTSSOP, SMS | not suitable <sup>(2)</sup>       | suitable              |
| PLCC <sup>(3)</sup> , SO, SOJ                | suitable                          | suitable              |
| LQFP, QFP, TQFP                              | not recommended <sup>(3)(4)</sup> | suitable              |
| SSOP, TSSOP, VSO                             | not recommended <sup>(5)</sup>    | suitable              |

#### Notes

- 1. All surface mount (SMD) packages are moisture sensitive. Depending upon the moisture content, the maximum temperature (with respect to time) and body size of the package, there is a risk that internal or external package cracks may occur due to vaporization of the moisture in them (the so called popcorn effect). For details, refer to the Drypack information in the "Data Handbook IC26; Integrated Circuit Packages; Section: Packing Methods".
- 2. These packages are not suitable for wave soldering as a solder joint between the printed-circuit board and heatsink (at bottom version) can not be achieved, and as solder may stick to the heatsink (on top version).
- 3. If wave soldering is considered, then the package must be placed at a 45° angle to the solder wave direction. The package footprint must incorporate solder thieves downstream and at the side corners.
- 4. Wave soldering is only suitable for LQFP, TQFP and QFP packages with a pitch (e) equal to or larger than 0.8 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.65 mm.
- 5. Wave soldering is only suitable for SSOP and TSSOP packages with a pitch (e) equal to or larger than 0.65 mm; it is definitely not suitable for packages with a pitch (e) equal to or smaller than 0.5 mm.

### DEFINITIONS

| Data sheet status         |   |
|---------------------------|---|
| Objective specification   | This data sheet contains target or goal specifications for product development.       |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification     | This data sheet contains final product specifications.                                |
| Limiting values           |   |

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

#### LIFE SUPPORT APPLICATIONS

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Printed in The Netherlands

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613507/01/pp16

Date of release: 2000 Mar 16

Document order number: 9397 750 06819

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